PNP/NPN Epitaxial Planar Silicon Transistors



2SB1167/2SD1724

100V/3A Switching Applications

Features

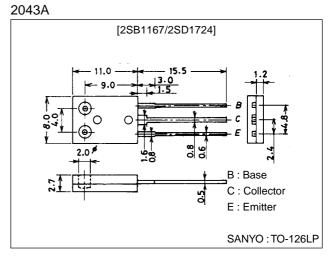
· Relay drivers, high-speed inverters, converters.

Features

- · Low collector-to-emitter saturation voltage.
- · High f_T.
- · Excellent linearity of h_{FE}.
- · Fast switching time.

Package Dimensions

unit:mm



():2SB1167

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(–)120	V
Collector-to-Emitter Voltage	VCEO		(–)100	V
Emitter-to-Base Voltage	VEBO		()6	V
Collector Current	ι _C		(–)3	A
Collector Current (Pulse)	ICP		(–)6	A
Collector Dissipation	PC		1.2	W
		Tc=25°C	20	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions							Unit					
Falameter	Symbol	Conditions					mi	n	typ	max	Unit			
Collector Cutoff Current	Ісво	V _{CB} =(-)100V, I _E =0										(–)1	μA	
Emitter Cutoff Current	IEBO	V _{EB} =(-)4V, I _C =0									(–)1	μA		
DC Current Gain	h _{FE} 1	V _{CE} =(-)5V, I _C =(-)0.5A						1	70*		400*			
	h _{FE} 2	V _{CE} =(-)5	√, I _C =	(–)2A							40			
Gain-Bandwidth Product	fT	V _{CE} =(-)10V, I _C =(-)0.5A							(130)		MHz			
												180		MHz
Output Capacitance	Cob	V _{CB} =(-)10V, f=1MHz 25(40)									pF			
* : The 2SB1167/2SD1724 are classified by 0.5A h_{FE} as follows :				Q	140	100	R	200	140	S	280	200	T 400	

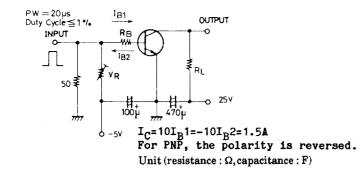
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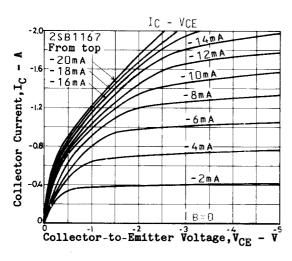
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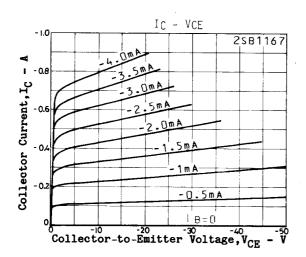
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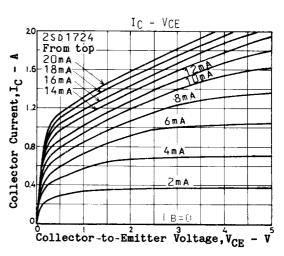
Parameter	Cumhal	Conditions		Ratings			
Parameter	Symbol	Conditions	min	typ	max	Unit	
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)1.5A, I _B =(-)0.15A		(-200)	(–500)	mV	
				150	400	mV	
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)1.5A, I _B =(-)0.15A		(–)0.9	(–)1.2	V	
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =(-)10μA, I _E =0	()120			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(−)1mA, R _{BE} =∞	()100			V	
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =(-)10μA, I _C =0	(–)6			V	
Turn-ON Time	ton	See specified Test Circuit		(100)		ns	
				100		ns	
Storage Time	t _{stg}	See specified Test Circuit		900		ns	
				(800)		ns	
Fall Time	tf	See specified Test Circuit		50(50)		ns	

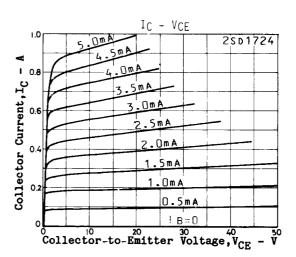
Switching Time Test Circuit

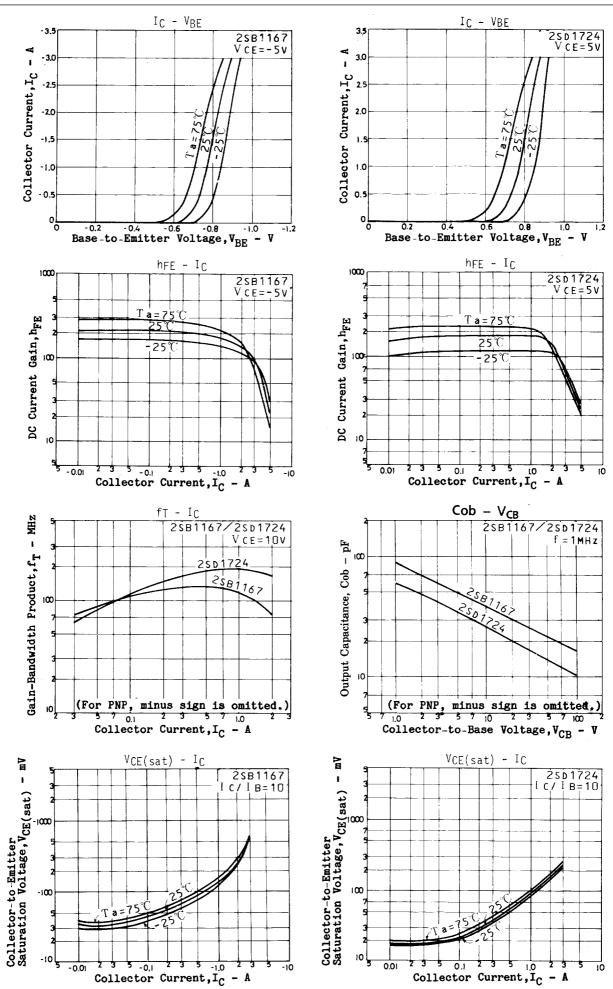




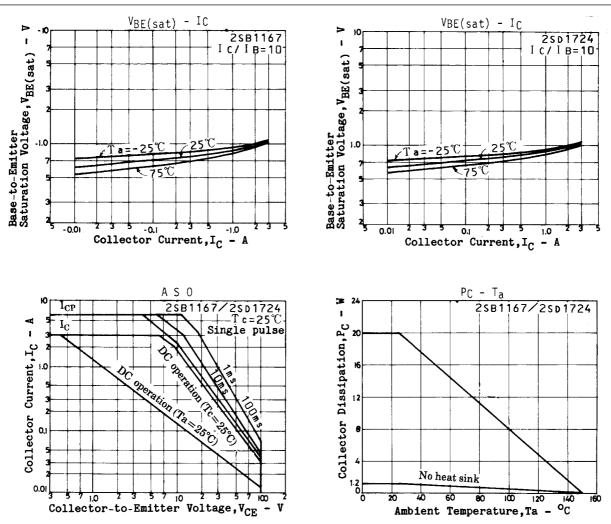








2SB1167/2SD1724



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